

780nm~785nm 100mW Single Mode LD| SM Laser Diode|5.6mm TO18 Package

785nm SM Infrared Laser Diodes |Single Mode LD | Built-in Photodiode

WSLD-785-100m-1-PD-R

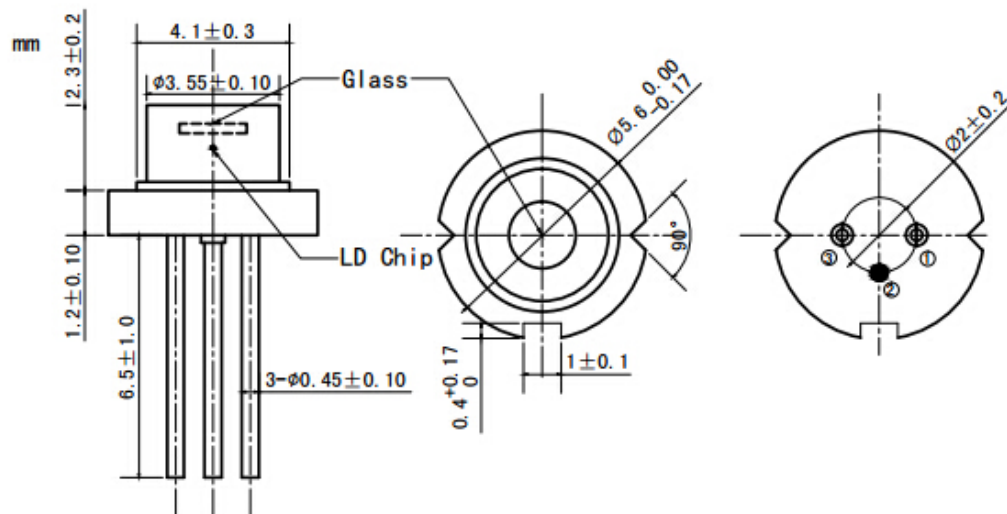
Wavespectrum laser Group

www.wavespectrum-laser.com

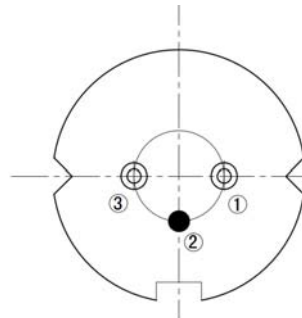
785nm Laser Diode PD		100mW/TO18	Wavespectrum Laser Group	
Reverse Voltage	V _r	2.0	V	
Operating Temperature	T _{op}	-20 ~ +60	°C	
Storage Temperature	T _{stg}	-40 ~ +85	°C	
Lead soldering temperature (5 sec.)	T _{is}	260	°C	
Features:				
Applications:				
Specifications		WSLD-785-100m-1-PD-R		
		Min	Type	Max
Center Wavelength@25℃		775nm	785nm	800nm
Spectral Width (FWHM)		2.0nm		
Output Power (CW)		100mW		
Recommend Operating Temperature		25℃		
Beam mode		Single Transverse Mode		
Beam Divergence (FWHM)		35° _⊥ x 5° _{//}	36° _⊥ x 9° _{//}	42° _⊥ x 12° _{//}
Monitor Current			0.2mA	
Slope Efficiency			0.9mW / mA	
Threshold Current (Typ.)			30mA	60mA
Operating Current (Typ.)			140mA	160mA
Operating Voltage			2.0V	2.4V
Package Style		TO18		
Photodiode		Built-in		



TO18(5.6mm) Package View



PIN Bottom View:



1	LD(+)
2	LD(-) & PD(+)
3	PD(-)

Electrically shorten LD module and store in non-extreme conditions.
Suggest using the constant current power supply.



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